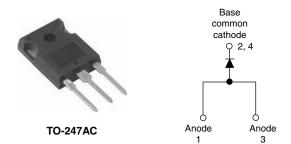


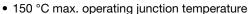
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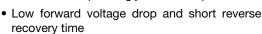
## Fast Soft Recovery Rectifier Diode, 80 A



PRODUCT SUMMARY					
Package	TO-247AC				
I <sub>F(AV)</sub>	80 A				
$V_{R}$	1000 V, 1200 V				
V <sub>F</sub> at I <sub>F</sub>	1.35 V				
I <sub>FSM</sub>	1100 A				
t <sub>rr</sub>	90 ns				
$T_J$ max.	150 °C				
Diode variation	Single die				
Snap factor	0.5				

#### **FEATURES**







 Designed and according qualified JEDEC-JESD47

RoHS

- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21

#### HALOGEN FREE

definition (-M3 only)

#### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

#### **DESCRIPTION**

The VS-80APF1... soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	TEST CONDITIONS	VALUES	UNITS				
V <sub>RRM</sub>		1000/1200	V				
I <sub>F(AV)</sub>	Sinusoidal waveform	80	^				
I <sub>FSM</sub>		1100	A				
t <sub>rr</sub>	1 A, - 100 A/μs	90	ns				
V <sub>F</sub>	40 A, T <sub>J</sub> = 25 °C	1.2	V				
T <sub>J</sub>		- 40 to 150	°C				

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-80APF10PbF, VS-80APF10-M3	1000	1100	12			
VS-80APF12PbF, VS-80APF12-M3	1200	1300	12			



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 92 °C, 180° conduction half sine wave	80		
Maximum peak one cycle		10 ms sine pulse, rated V <sub>RRM</sub> applied	1100 A		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1250		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	5000	A <sup>2</sup> s	
		10 ms sine pulse, no voltage reapplied	7000	A-S	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	70 000	A²√s	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	80 A, T <sub>J</sub> = 25 °C		1.35	V
Forward slope resistance	r <sub>t</sub>	T 150 °C		4.03	mΩ
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = 150 °C		0.87	V
Maximum reverse leakage current	I	T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	mA
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR - Hateu VRRM	12	IIIA

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	1
Reverse recovery time	t <sub>rr</sub>	Is at 80 Apr	480	ns	I <sub>FM</sub> t
Reverse recovery current	I <sub>rr</sub>	I <sub>F</sub> at 80 A <sub>pk</sub> 25 Α/μs	7.1	Α	
Reverse recovery charge	Q <sub>rr</sub>	25 °C	2.1	μC	dir/ dt Q <sub>rr</sub>
Snap factor	S		0.5		I <sub>RM(REC)</sub>

THERMAL - MEC	THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.35	
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2	
A				6	g
Approximate weight	Approximate weight			0.21	oz.
minimur				6 (5)	kgf · cm
Mounting torque m	maximum			12 (10)	(lbf ⋅ in)
Marking daviso	Maddandada		0	1A08	PF10
Marking device			Case style TO-247AC	80APF12	





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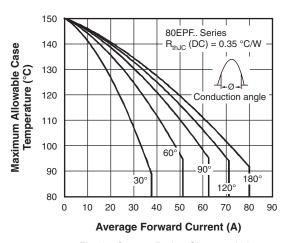


Fig. 1 - Current Rating Characteristics

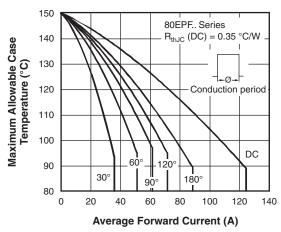


Fig. 2 - Current Rating Characteristics

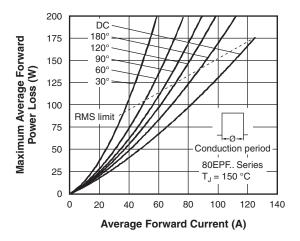


Fig. 3 - Forward Power Loss Characteristics

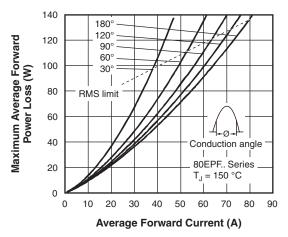


Fig. 4 - Forward Power Loss Characteristics

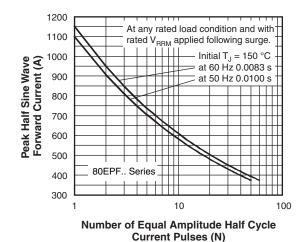


Fig. 5 - Maximum Non-Repetitive Surge Current

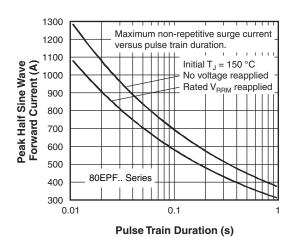


Fig. 6 - Maximum Non-Repetitive Surge Current

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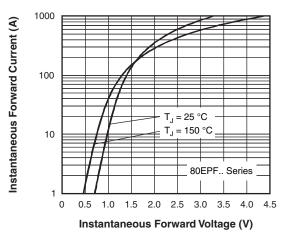


Fig. 7 - Forward Voltage Drop Characteristics

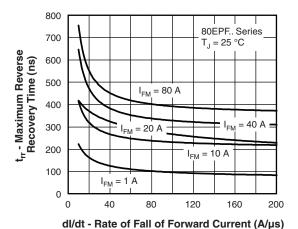


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

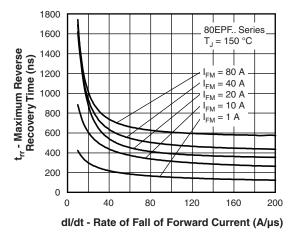
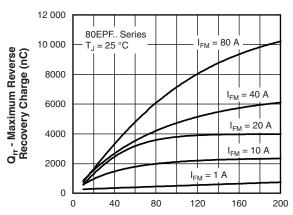
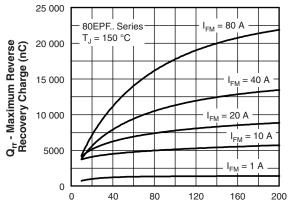


Fig. 9 - Recovery Time Characteristics, T<sub>J</sub> = 150 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C



dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C



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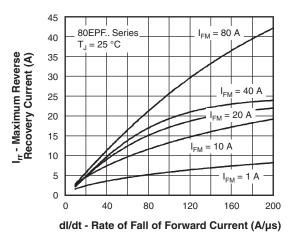
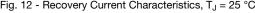


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

60 I<sub>FM</sub> = 80 A 80EPF.. Series T<sub>.1</sub> = 150 °C 50 Irr - Maximum Reverse Recovery Current (A) = 40 A40  $I_{FM} = 20 \text{ A}$ 30 20 = 10 A10  $I_{FM} = 1 A$ 0 200

dl/dt - Rate of Fall of Forward Current (A/µs) Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C



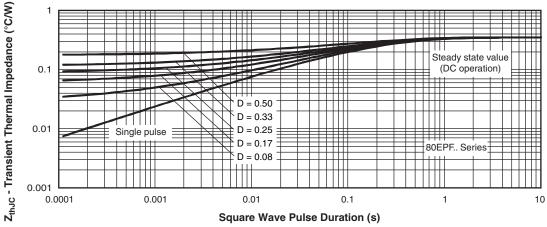
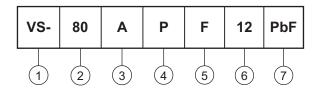


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

- Circuit configuration:

A = Single diode, 3 pins

4 - Package:

P = TO-247AC

5 - Type of silicon:

F = Fast recovery

6 - Voltage code x 100 = V<sub>RRM</sub> - 10 = 1000 V 12 = 1200 V

7 - Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-80APF10PbF	25	500	Antistatic plastic tubes			
VS-80APF10-M3	25	500	Antistatic plastic tubes			
VS-80APF12PbF	25	500	Antistatic plastic tubes			
VS-80APF12-M3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95223		
Dout moulting information	TO-247AC PbF	www.vishay.com/doc?95226		
Part marking information	TO-247AC -M3	www.vishay.com/doc?95007		



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.